Preferred Device

General Purpose Transistor

NPN Silicon

These transistors are designed for general purpose amplifier applications. They are housed in the SOT-323/SC-70 package which is designed for low power surface mount applications.

Features

• Pb-Free Package is Available

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|--------------------------------|------------------|-------|------|
| Collector - Emitter Voltage | V _{CEO} | 40 | Vdc |
| Collector - Base Voltage | V _{CBO} | 75 | Vdc |
| Emitter – Base Voltage | V _{EBO} | 6.0 | Vdc |
| Collector Current – Continuous | Ic | 600 | mAdc |

THERMAL CHARACTERISTICS

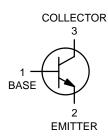
| Characteristic | Symbol | Max | Unit |
|---|-----------------------------------|-------------|------|
| Total Device Dissipation FR-5 Board T _A = 25°C | P _D | 150 | mW |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 833 | °C/W |
| Junction and Storage Temperature | T _J , T _{stg} | -55 to +150 | °C |

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



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SC-70 CASE 419 STYLE 3

MARKING DIAGRAM



P1 = Specific Device Code

M = Date Code*

= Pb-Free Package

(Note: Microdot may be in either location)
*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|---------------|--------------------|-----------------------|
| MMBT2222AWT1 | SC-70 | 3000/Tape & Reel |
| MMBT2222AWT1G | SC-70 (Pb-Free) | 3000/Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

| Charac | cteristic | Symbol | Min | Max | Unit | |
|---|---|----------------------|-----------------------------|-------------------------|------|--|
| OFF CHARACTERISTICS | | | | | | |
| ollector – Emitter Breakdown Voltage (Note 1) (I _C = 1.0 mAdc, I _B = 0) | | V _{(BR)CEO} | 40 | _ | Vdc | |
| Collector – Base Breakdown Voltage ($I_C = 10 \mu Adc, I_E = 0$) | | | 75 | _ | Vdc | |
| Emitter – Base Breakdown Voltage ($I_E = 10 \mu Adc, I_C = 0$) | | V _{(BR)EBO} | 6.0 | _ | Vdc | |
| Base Cutoff Current (V _{CE} = 60 Vdc, V _{EB} = 3.0 Vdc) | | | - | 20 | nAdc | |
| Collector Cutoff Current (V _{CE} = 60 Vdc, V _{EB} = 3.0 Vdc) | | I _{CEX} | - | 10 | nAdc | |
| ON CHARACTERISTICS (Note 1) | | - | | • | | |
| DC Current Gain (Note 1) $ \begin{aligned} &(I_C = 0.1 \text{ mAdc, } V_{CE} = 10 \text{ Vdc}) \\ &(I_C = 1.0 \text{ mAdc, } V_{CE} = 10 \text{ Vdc}) \\ &(I_C = 10 \text{ mAdc, } V_{CE} = 10 \text{ Vdc}) \\ &(I_C = 150 \text{ mAdc, } V_{CE} = 10 \text{ Vdc}) \\ &(I_C = 500 \text{ mAdc, } V_{CE} = 10 \text{ Vdc}) \end{aligned} $ | | H _{FE} | 35 50 75 100 40 | - - - 300 - | - | |
| Collector – Emitter Saturation Voltage (Note 1) (I _C = 150 mAdc, I _B = 15 mAdc) (I _C = 500 mAdc, I _B = 50 mAdc) | | V _{CE(sat)} | _ _ | 0.3 1.0 | Vdc | |
| $\begin{aligned} \text{Base-Emitter Saturation Voltage (Note 1)} \\ \text{(I}_{\text{C}} &= 150 \text{ mAdc, I}_{\text{B}} = 15 \text{ mAdc)} \\ \text{(I}_{\text{C}} &= 500 \text{ mAdc, I}_{\text{B}} = 50 \text{ mAdc)} \end{aligned}$ | | V _{BE(sat)} | 0.6 | 1.2 2.0 | Vdc | |
| SMALL-SIGNAL CHARACTERISTICS | | | | | | |
| Current-Gain - Bandwidth Product (I _C = 20 mAdc, V _{CE} = 20 Vdc, f = 100 M | Hz) | f _T | 300 | _ | MHz | |
| Output Capacitance ($V_{CB} = 10 \text{ Vdc}$, $I_E = 0$, $f = 1.0 \text{ MHz}$) | | C _{obo} | _ | 8.0 | pF | |
| Input Capacitance ($V_{EB} = 0.5 \text{ Vdc}$, $I_{C} = 0$, $f = 1.0 \text{ MHz}$) | | C _{ibo} | _ | 30 | pF | |
| Input Impedance ($V_{CE} = 10 \text{ Vdc}$, $I_{C} = 10 \text{ mAdc}$, $f = 1.0 \text{ kH}$ | h _{ie} | 0.25 | 1.25 | kΩ | | |
| Voltage Feedback Ratio (V _{CE} = 10 Vdc, I _C = 10 mAdc, f = 1.0 kH | h _{re} | _ | 4.0 | X 10 ⁻⁴ | | |
| Small – Signal Current Gain (V _{CE} = 10 Vdc, I _C = 10 mAdc, f = 1.0 kH | h _{fe} | 75 | 375 | _ | | |
| Output Admittance (V _{CE} = 10 Vdc, I _C = 10 mAdc, f = 1.0 kH | h _{oe} | 25 | 200 | μmhos | | |
| Noise Figure ($V_{CE} = 10 \text{ Vdc}, I_{C} = 100 \mu\text{Adc}, R_{S} = 1.0$ | NF | - | 4.0 | dB | | |
| SWITCHING CHARACTERISTICS | | | | | | |
| Delay Time | $(V_{CC} = 3.0 \text{ Vdc}, V_{BE} = -0.5 \text{ Vdc},$ | t _d | _ | 10 | no | |
| Rise Time | I _C = 150 mAdc, I _{B1} = 15 mAdc) | t _r | _ | 25 | ns | |
| Storage Time | (V _{CC} = 30 Vdc, I _C = 150 mAdc, | t _s | - | 225 | - ns | |
| Fall Time | $I_{B1} = I_{B2} = 15 \text{ mAdc}$ | t _f | - | 60 | 113 | |

^{1.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

SWITCHING TIME EQUIVALENT TEST CIRCUITS

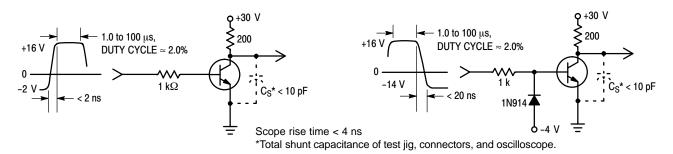


Figure 1. Turn-On Time

Figure 2. Turn-Off Time

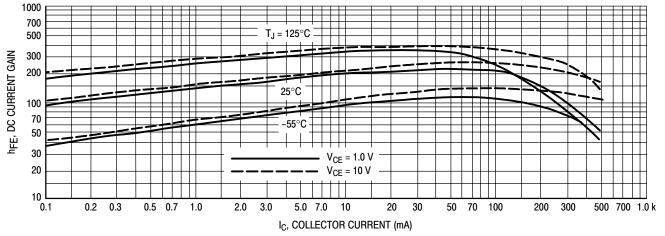


Figure 3. DC Current Gain

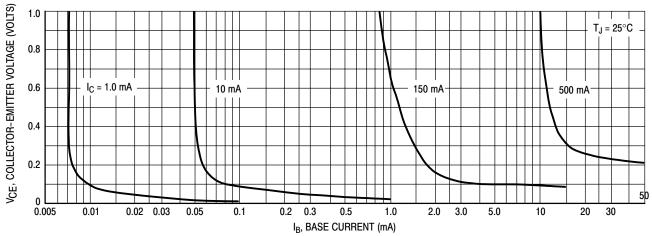


Figure 4. Collector Saturation Region

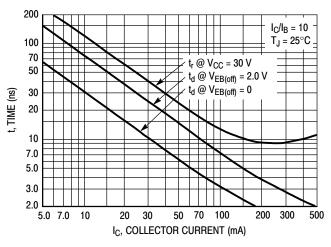


Figure 5. Turn-On Time

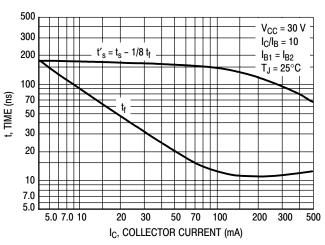


Figure 6. Turn-Off Time

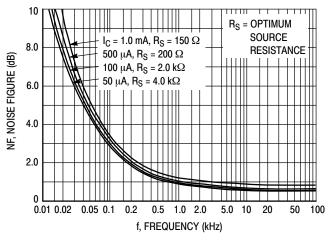


Figure 7. Frequency Effects

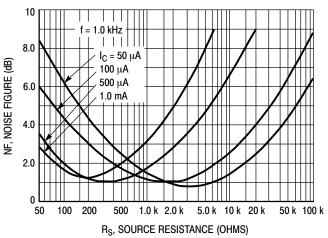


Figure 8. Source Resistance Effects

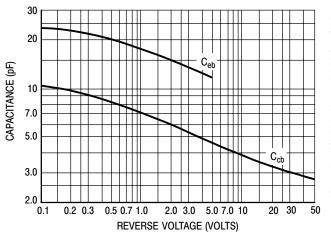


Figure 9. Capacitances

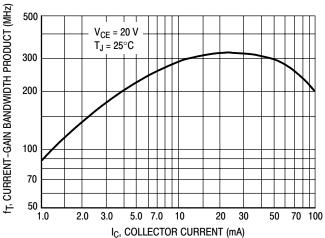


Figure 10. Current-Gain Bandwidth Product

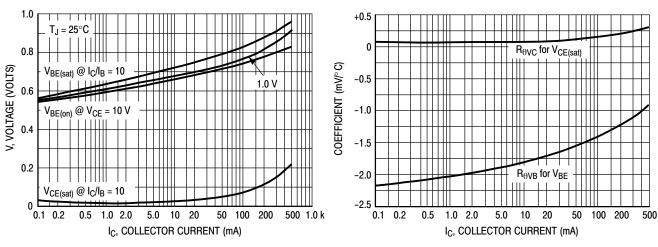
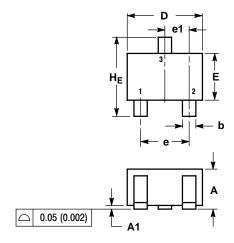


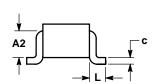
Figure 11. "On" Voltages

Figure 12. Temperature Coefficients

PACKAGE DIMENSIONS

SC-70 (SOT-323) CASE 419-04 ISSUE M





NOTES:

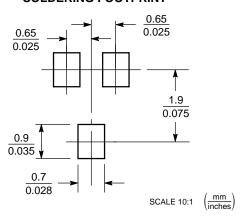
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.

| | MILLIMETERS | | | INCHES | | |
|-----|--------------------|------|------|-----------|-------|-------|
| DIM | MIN | NOM | MAX | MIN | MON | MAX |
| Α | 0.80 | 0.90 | 1.00 | 0.032 | 0.035 | 0.040 |
| A1 | 0.00 | 0.05 | 0.10 | 0.000 | 0.002 | 0.004 |
| A2 | 0.7 REF | | | 0.028 REF | | |
| b | 0.30 | 0.35 | 0.40 | 0.012 | 0.014 | 0.016 |
| С | 0.10 | 0.18 | 0.25 | 0.004 | 0.007 | 0.010 |
| D | 1.80 | 2.10 | 2.20 | 0.071 | 0.083 | 0.087 |
| E | 1.15 | 1.24 | 1.35 | 0.045 | 0.049 | 0.053 |
| е | 1.20 | 1.30 | 1.40 | 0.047 | 0.051 | 0.055 |
| e1 | 0.65 BSC 0.026 BSC | | | ; | | |
| L | 0.425 REF | | | 0.017 REF | | |
| HE | 2.00 | 2.10 | 2.40 | 0.079 | 0.083 | 0.095 |

STYLE 3:

PIN 1. BASE 2. EMITTER 3. COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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